Student ID #:_____

EECS 170A Homework #4

HW will be collected in discussion section. Please do not turn your HW in anywhere else. Due: Noon Thursday, October 27, 2011.

Please *staple* this sheet to the front of your homework.

1	2	3	4	Total
/25	/25	/25	/25	/100

- 1) Given Si at room temperature at equilibrium. $N_D = 0$, $N_A(x) = 10^{16}$ cm⁻³ for x < 0 and $N_A(x) = 10^{17}$ cm⁻³ for x > 1µm with a smooth gradual variation in between.
 - a) Sketch and find: Hole Concentration p(x), Electron Concentration n(x), Electric Field E(x), J_{ndiff}(x), J_{ndiff}(x), J_{pdiff}(x), J_{pdiff}(x).
 - b) Sketch the Band Diagram.
 - c) Which current components are the largest? Which are the smallest?
- 2) Given the following Band Diagram:



- a) Sketch and find: Hole Concentration p(x), Electron Concentration n(x), Electric Field E(x), J_{ndiff}(x), J_{pdiff}(x), J_{pdiff}(x), J_{pdiff}(x).
- b) Assume $N_D = 0$. Find N_A in cm⁻³ the left hand side.
- 3) Given the following expression for electron concentration: $n(x) = n_0 * e^{-x/L_0}$ where $n_0 = 10^{18} \text{cm}^{-3}$ and $L_0 = 1 \mu \text{m}$.

Find $J_{ndrift}(x)$.

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- 4) For the Band Diagram below:
 - a) Find: Hole Concentration p(x), Electron Concentration n(x), Electric Field E(x),
 - $J_{ndiff}(x), J_{ndrift}(x), J_{pdiff}(x), J_{pdrift}(x).$ b) Find N_D(x) assuming N_A(x) = 0.

